

Designer's™ Data Sheet

High Speed, High Gain Bipolar NPN Transistor Integrating an Antisaturation Network and a Transient Voltage Suppression Capability

The BUD42D is a state-of-the-art bipolar transistor. Tight dynamic characteristics and lot to lot minimum spread make it ideally suited to light ballast applications.

Main features:

- Free Wheeling Diode built in
- Flat DC Current Gain
- Fast Switching Times and Tight Distribution
- "6 Sigma" Process Providing Tight and Reproducible Parameter Spreads

Two versions:

- BUD42D-1: Case 369-07 for Insertion Mode
- BUD42D: Case 369A-13 for Surface Mount Mode

MAXIMUM RATINGS

Parameters	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V_{CEO}	350	Vdc
Collector-Base Breakdown Voltage	V_{CBO}	650	Vdc
Collector-Emitter Breakdown Voltage	V_{CES}	650	Vdc
Emitter-Base Voltage	V_{EBO}	9	Vdc
Collector Current — Continuous	I_C	4	Adc
— Peak (1)	I_{CM}	8	
Base Current — Continuous	I_B	1	Adc
— Peak (1)	I_{BM}	2	
*Total Device Dissipation @ $T_C = 25^\circ\text{C}$	P_D	25	Watt
*Derate above 25°C		0.2	W/ $^\circ\text{C}$
Operating and Storage Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

TYPICAL GAIN

Typical Gain @ $I_C = 1\text{ A}$, $V_{CE} = 2\text{ V}$	h_{FE}	13	—
Typical Gain @ $I_C = 0.3\text{ A}$, $V_{CE} = 1\text{ V}$	h_{FE}	16	—

THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Case	$R_{\theta JC}$	5	$^\circ\text{C/W}$
— Junction to Ambient	$R_{\theta JA}$	71.4	
Maximum Lead Temperature for Soldering Purposes: 1/8" from case for 5 seconds	T_L	260	$^\circ\text{C}$

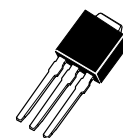
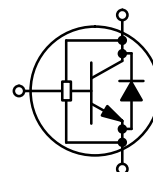
(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

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Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

BUD42D

POWER TRANSISTORS
4 AMPERES
650 VOLTS
25 WATTS

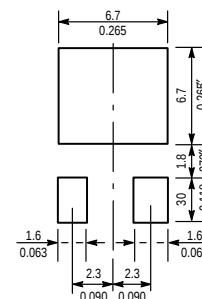


CASE 369-07



CASE 369A-13

MINIMUM PAD SIZES
RECOMMENDED FOR
SURFACE MOUNTED
APPLICATIONS



ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage ($I_C = 100\text{ mA}$, $L = 25\text{ mH}$)	$V_{CEO(sus)}$	350	430		Vdc
Collector–Base Breakdown Voltage ($I_{CBO} = 1\text{ mA}$)	V_{CBO}	650	780		Vdc
Emitter–Base Breakdown Voltage ($I_{EBO} = 1\text{ mA}$)	V_{EBO}	9	12		Vdc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CEO}$, $I_B = 0$)	I_{CEO}			100 200	μAdc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CES}$, $V_{EB} = 0$)	I_{CES}			10 200	μAdc
Emitter–Cutoff Current ($V_{EB} = 9\text{ Vdc}$, $I_C = 0$)	I_{EBO}			100	μAdc

ON CHARACTERISTICS

Base–Emitter Saturation Voltage ($I_C = 1\text{ Adc}$, $I_B = 0.2\text{ Adc}$)	$V_{BE(sat)}$		0.85	1.2	Vdc
Collector–Emitter Saturation Voltage ($I_C = 2\text{ Adc}$, $I_B = 0.5\text{ Adc}$)	$V_{CE(sat)}$		0.2	1	Vdc
DC Current Gain ($I_C = 1\text{ Adc}$, $V_{CE} = 2\text{ Vdc}$) ($I_C = 2\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	h_{FE}	8 10	13 12		—

DIODE CHARACTERISTICS

Forward Diode Voltage ($I_{EC} = 1.0\text{ Adc}$)	V_{EC}		0.9	1.5	V
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SWITCHING CHARACTERISTICS: Resistive Load (D.C. $\leq 10\%$, Pulse Width = $40\text{ }\mu\text{s}$)

Turn–Off Time ($I_C = 1.2\text{ Adc}$, $I_{B1} = 0.4\text{ A}$, $I_{B2} = 0.1\text{ A}$, $V_{CC} = 300\text{ V}$)	T_{off}	4.6		6.55	μs
Fall Time ($I_C = 2.5\text{ Adc}$, $I_{B1} = I_{B2} = 0.5\text{ A}$, $V_{CC} = 150\text{ V}$, $V_{BE} = -2\text{ V}$)	T_f			0.8	μs

DYNAMIC SATURATION VOLTAGE

Dynamic Saturation Voltage: Determined $1\text{ }\mu\text{s}$ and $3\text{ }\mu\text{s}$ respectively after rising I_{B1} reaches 90% of final I_{B1}	$I_C = 400\text{ mA}$ $I_{B1} = 40\text{ mA}$ $V_{CC} = 300\text{ V}$	@ $1\text{ }\mu\text{s}$	@ $T_C = 25^\circ\text{C}$ @ $T_C = 125^\circ\text{C}$	$V_{CE(dsat)}$		2.8 3.2		V
		@ $3\text{ }\mu\text{s}$	@ $T_C = 25^\circ\text{C}$ @ $T_C = 125^\circ\text{C}$			0.75 1.3		
	$I_C = 1\text{ A}$ $I_{B1} = 200\text{ mA}$ $V_{CC} = 300\text{ V}$	@ $1\text{ }\mu\text{s}$	@ $T_C = 25^\circ\text{C}$ @ $T_C = 125^\circ\text{C}$			2.1 4.7		
		@ $3\text{ }\mu\text{s}$	@ $T_C = 25^\circ\text{C}$ @ $T_C = 125^\circ\text{C}$			0.35 0.6		

TYPICAL STATIC CHARACTERISTICS

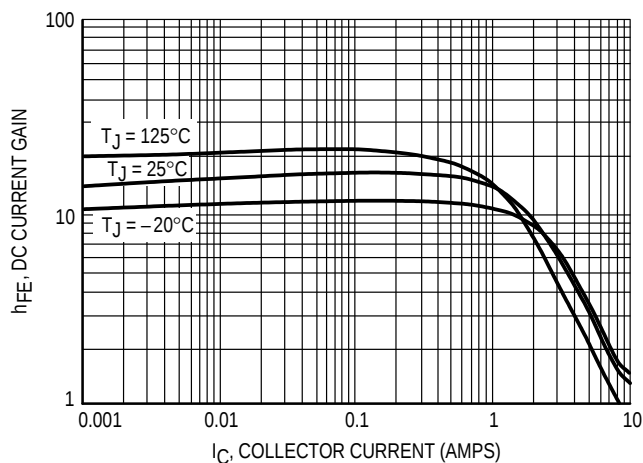
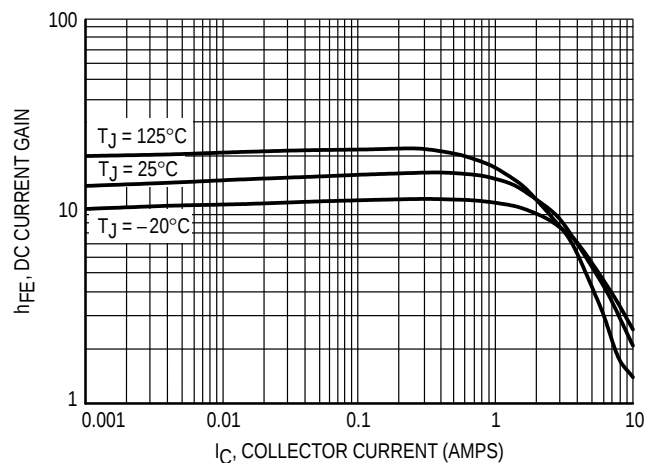
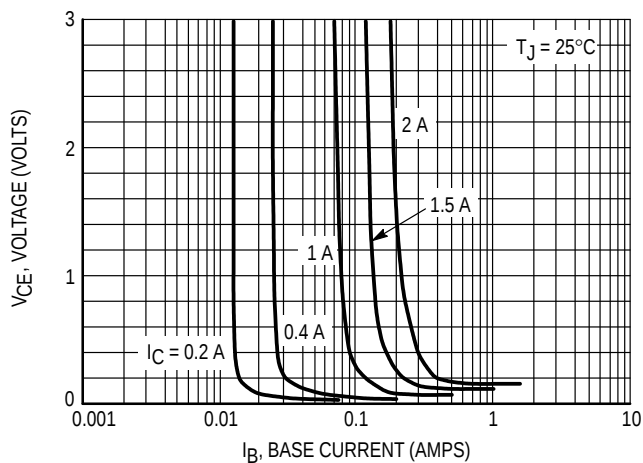
Figure 1. DC Current Gain @ $V_{CE} = 1\text{ V}$ Figure 2. DC Current Gain @ $V_{CE} = 5\text{ V}$ 

Figure 3. Collector Saturation Region

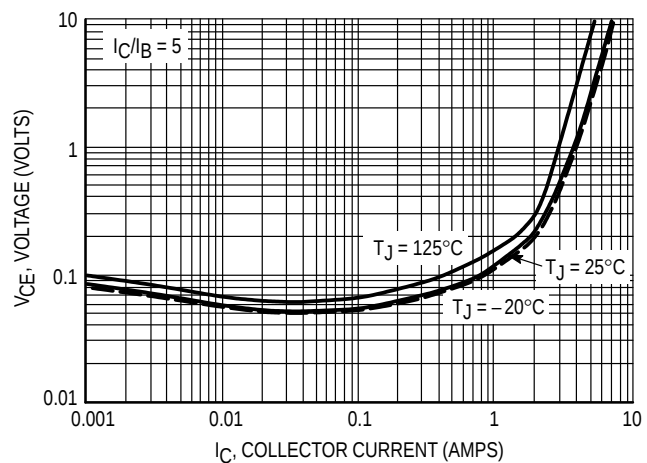


Figure 4. Collector-Emitter Saturation Voltage

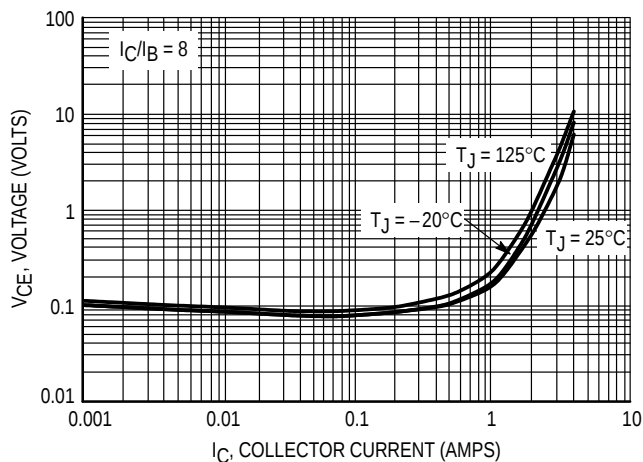


Figure 5. Collector-Emitter Saturation Voltage

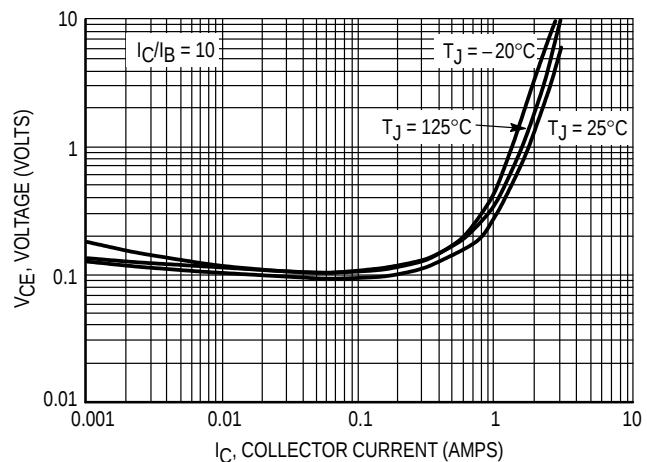


Figure 6. Collector-Emitter Saturation Voltage

TYPICAL STATIC CHARACTERISTICS

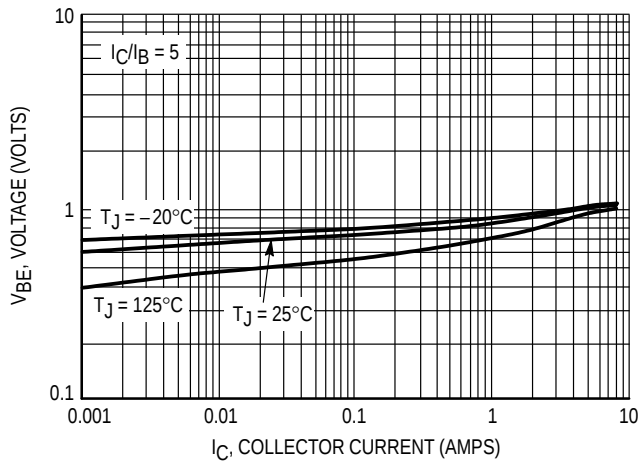


Figure 7. Base-Emitter Saturation Region

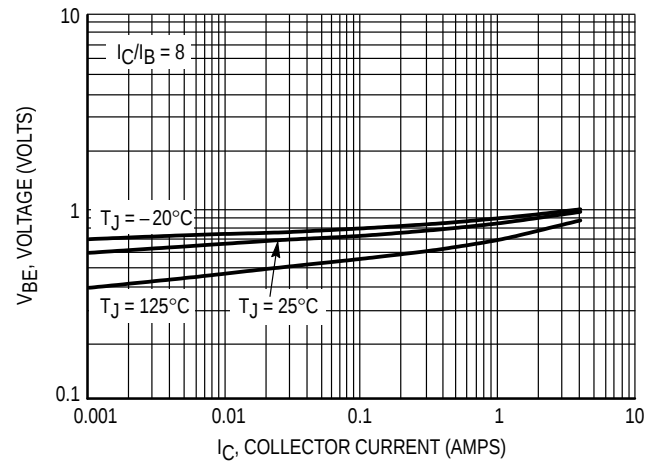


Figure 8. Base-Emitter Saturation Region

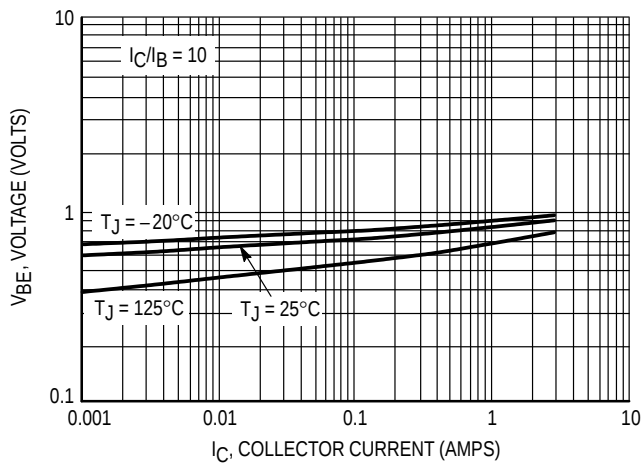


Figure 9. Base-Emitter Saturation Region

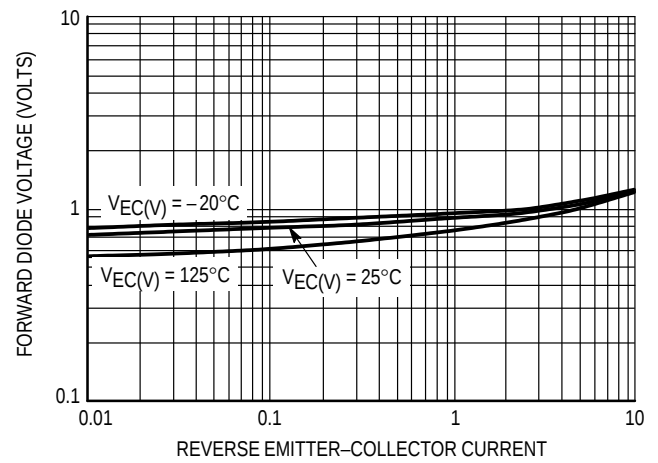


Figure 10. Forward Diode Voltage

TYPICAL SWITCHING CHARACTERISTICS

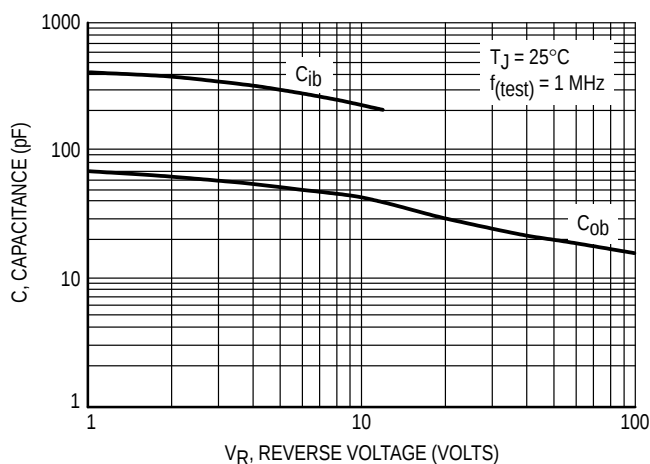
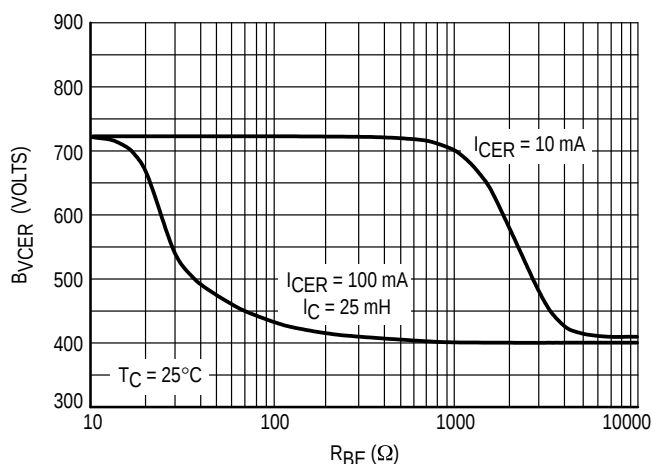
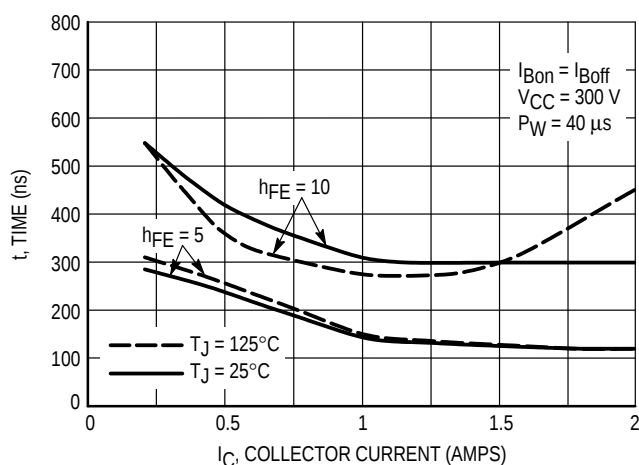
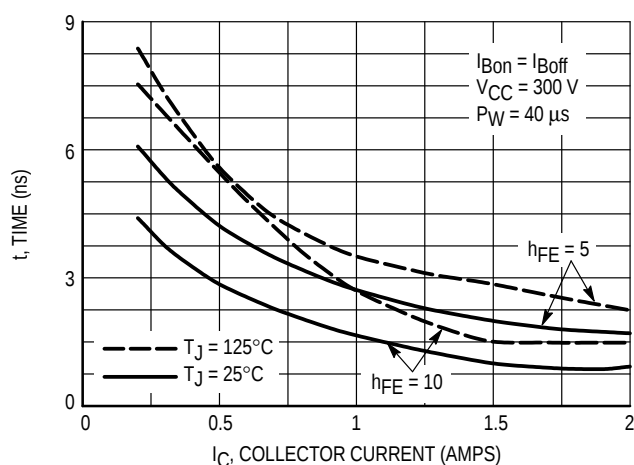
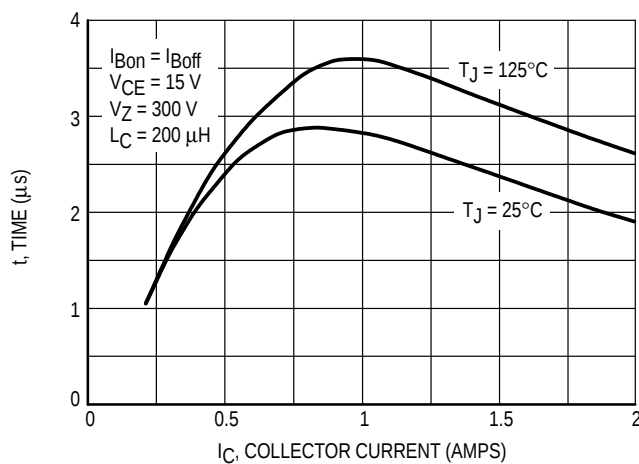
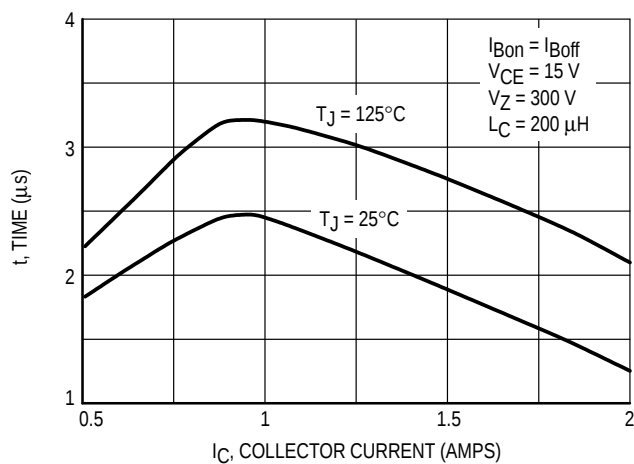


Figure 11. Capacitance

Figure 12. $BV_{CEr} = f(R_B)$ Figure 13. Resistive Switching, t_{on} Figure 14. Resistive Switching, t_{off} Figure 15. Inductive Storage Time,
 t_{si} @ $h_{FE} = 5$ Figure 16. Inductive Storage Time,
 t_{si} @ $h_{FE} = 10$

TYPICAL SWITCHING CHARACTERISTICS

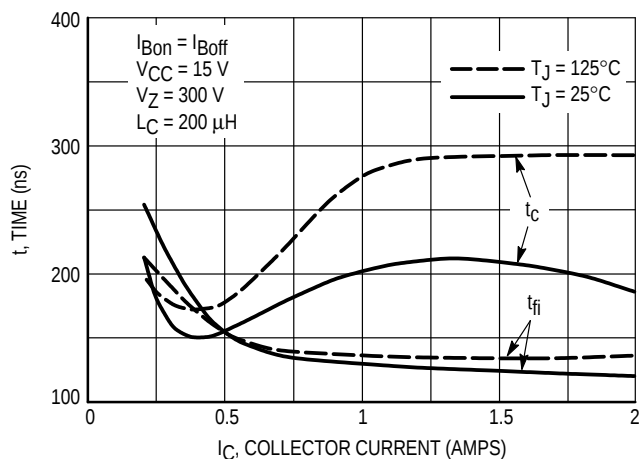


Figure 17. Inductive Fall and Cross Over Time, t_{fi} and t_c @ $h_{FE} = 5$

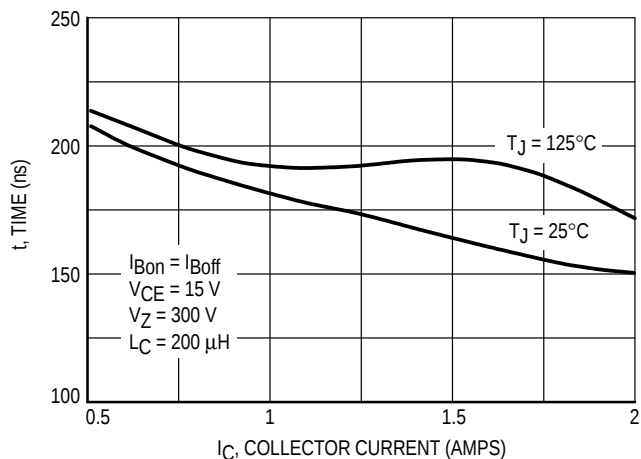


Figure 18. Inductive Fall Time, t_{fi} @ $h_{FE} = 10$

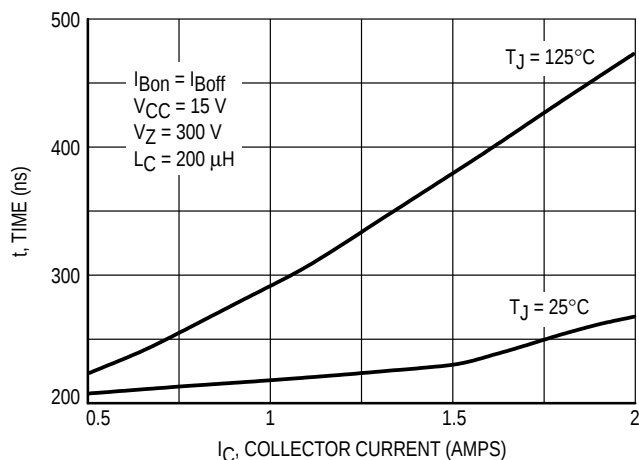


Figure 19. Inductive Cross Over Time, t_c @ $h_{FE} = 10$

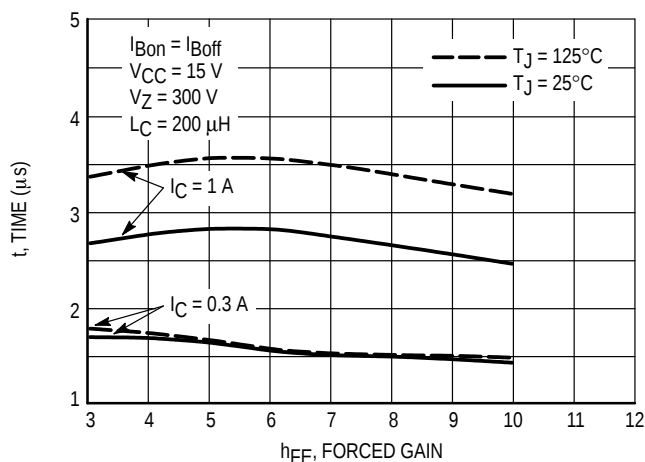


Figure 20. Inductive Storage Time, t_{sj}

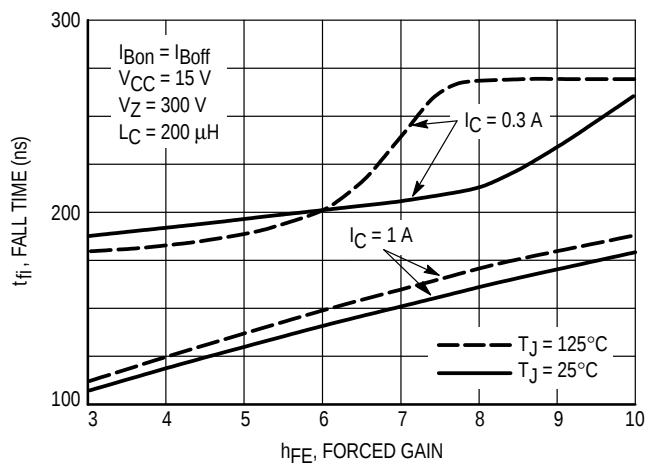


Figure 21. Inductive Fall Time, t_f

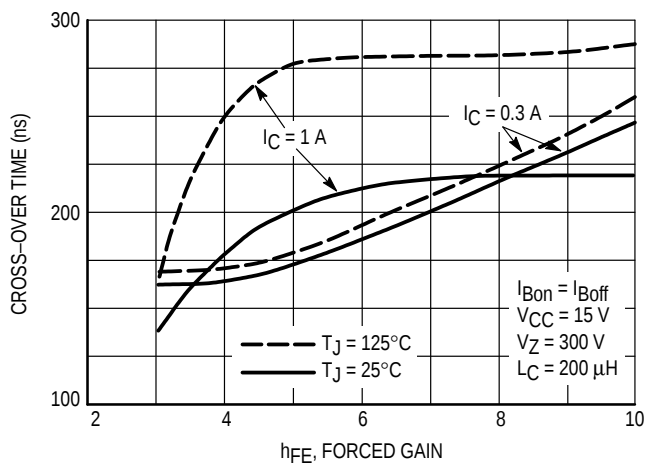


Figure 22. Inductive Cross Over Time, t_c

TYPICAL SWITCHING CHARACTERISTICS

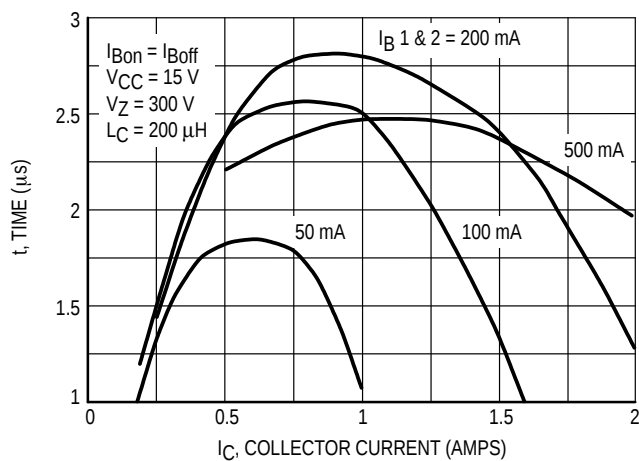
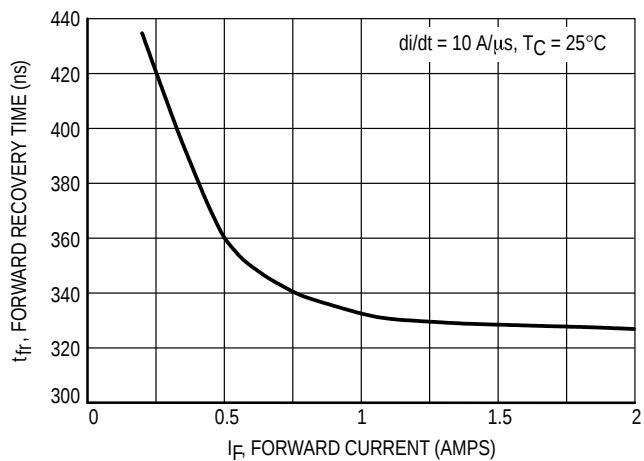
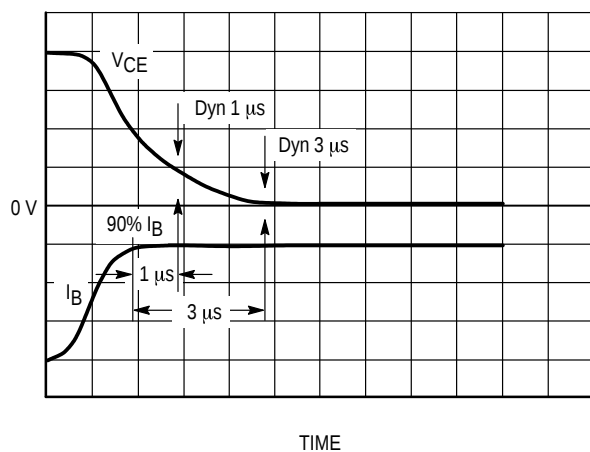
Figure 23. Inductive Storage Time, t_{si} Figure 24. Forward Recovery Time, t_{fr} 

Figure 25. Dynamic Saturation Voltage Measurements

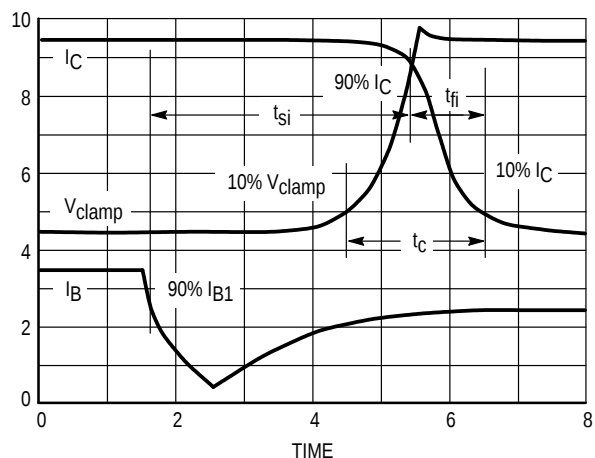


Figure 26. Inductive Switching Measurements

TYPICAL SWITCHING CHARACTERISTICS

Table 1. Inductive Load Switching Drive Circuit

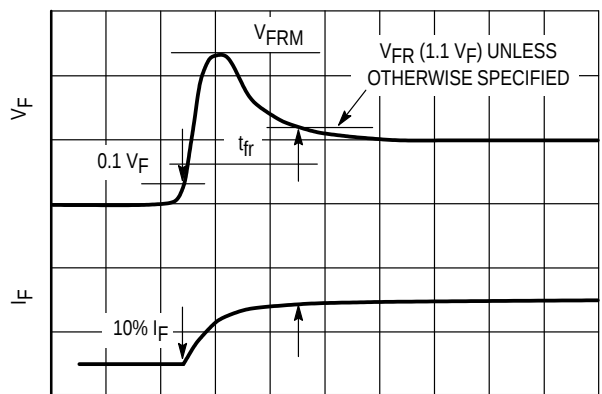
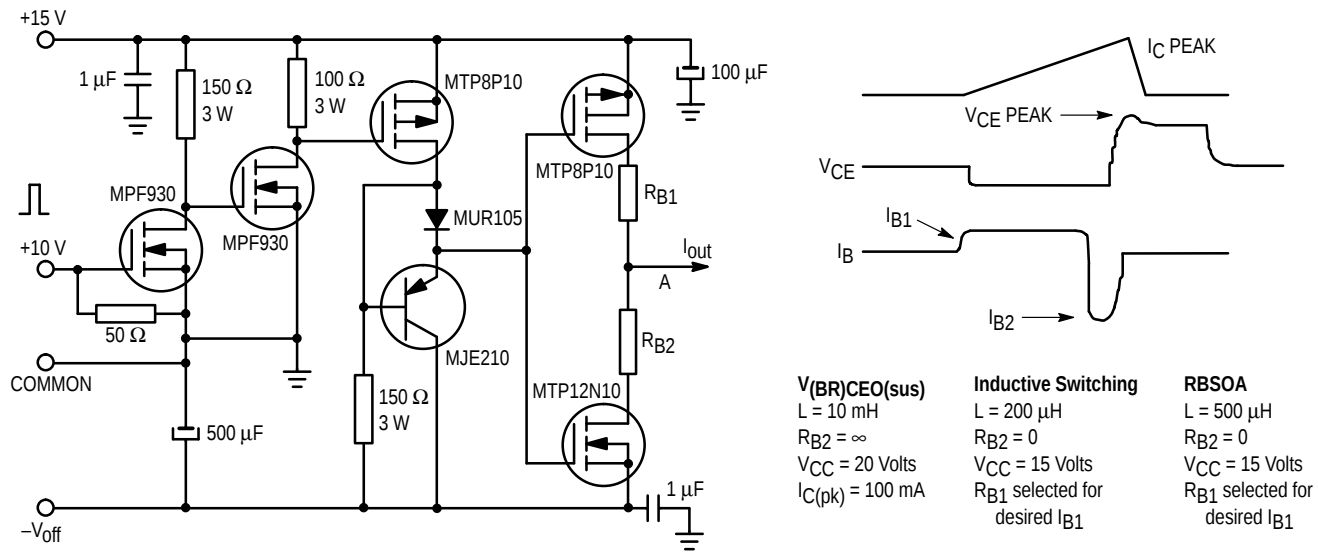


Figure 27. t_{fr} Measurement

MAXIMUM RATINGS

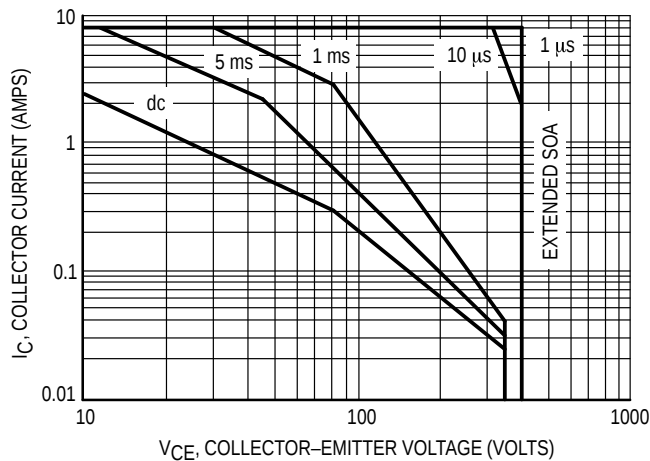


Figure 28. Forward Bias Safe Operating Area

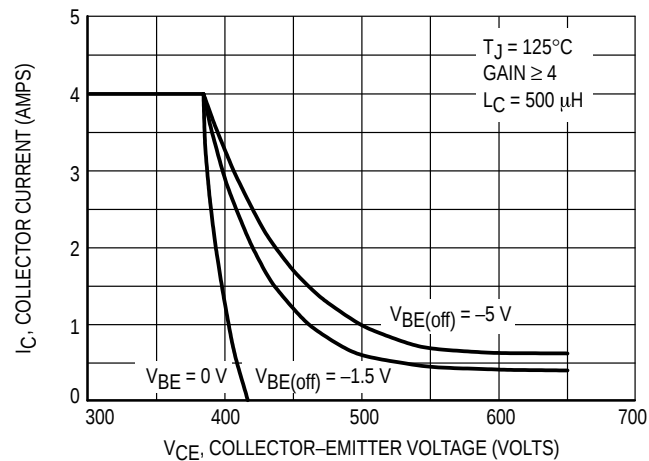


Figure 29. Reverse Bias Safe Operating Area

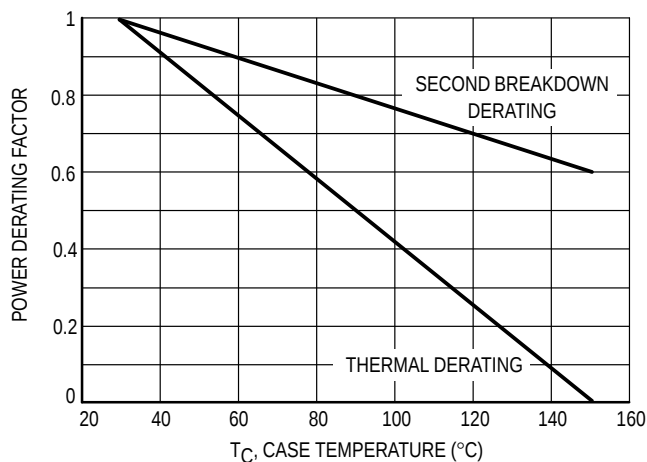


Figure 30. Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C - V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Figure 28 is based on $T_C = 25^\circ\text{C}$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C > 25^\circ\text{C}$. Second Breakdown limitations do not derate like thermal limitations. Allowable current at the voltages shown on Figure 28 may be

found at any case temperature by using the appropriate curve on Figure 30.

$T_{J(pk)}$ may be calculated from the data in Figure 31. At any case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. For inductive loads, high voltage and current must be sustained simultaneously during turn-off with the base to emitter junction reverse biased. The safe level is specified as reverse biased safe operating area (Figure 29). This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode.

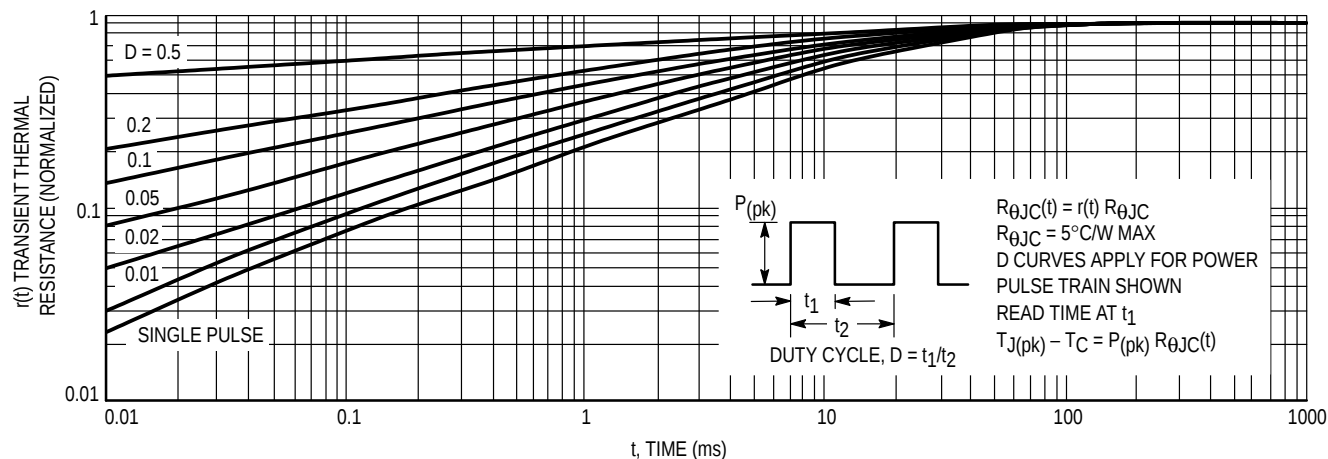
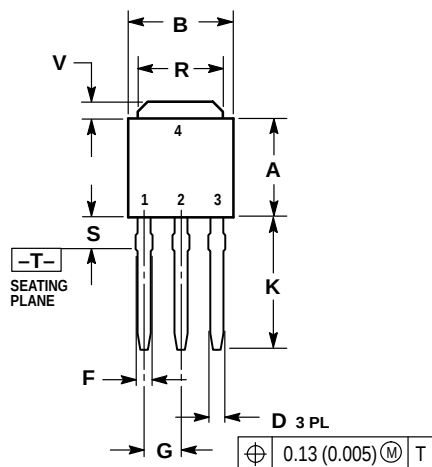


Figure 31. Thermal Response

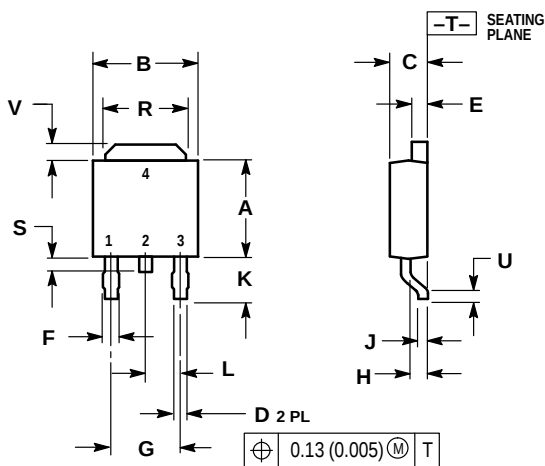
PACKAGE DIMENSIONS

CASE 369-07
ISSUE L

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.175	0.215	4.45	5.46
S	0.050	0.090	1.27	2.28
V	0.030	0.050	0.77	1.27

- STYLE 1:
- PIN 1. BASE
 - COLLECTOR
 - EMITTER
 - COLLECTOR

CASE 369A-13
ISSUE Z

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020	—	0.51	—
V	0.030	0.050	0.77	1.27
Z	0.138	—	3.51	—

- STYLE 1:
- PIN 1. BASE
 - COLLECTOR
 - EMITTER
 - COLLECTOR

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MOTOROLA

